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Fano-Liouville Spectral Signatures in Open Quantum Systems

Daniel Finkelstein-Shapiro,^{1,2,3} Ines Urdaneta,^{2,3,4} Monica Calatayud,^{2,3,5} Osman Atabek,⁴ Vladimiro Mujica,¹ and Arne Keller⁴

¹*Department of Chemistry and Biochemistry, Arizona State University, Tempe AZ 85282*

²*Sorbonne Universités, UPMC Univ Paris 06, UMR 7616, Laboratoire de Chimie Théorique, F-75005, Paris, France*

³*CNRS, UMR 7616, Laboratoire de Chimie Théorique, F-75005, Paris, France*

⁴*Institut des Sciences Moléculaires d'Orsay, Bâtiment 350, UMR8214, CNRS-Université Paris-Sud, 91405 Orsay, France*

⁵*Institut Universitaire de France, France*

The scattering amplitude from a set of discrete states coupled to a continuum became known as the Fano profile, characteristic for its asymmetric lineshape and originally investigated in the context of photoionization. The generality of the model, and the proliferation of engineered nanostructures with confined states gives immense success to the Fano lineshape, which is invoked whenever an asymmetric lineshape is encountered. However, many of these systems do not conform to the initial model worked out by Fano in that i) they are subject to dissipative processes and ii) the observables are not entirely analogous to the ones measured in the original photoionization experiments. In this letter, we work out the full optical response of a Fano model with dissipation. We find that the exact result for the excited population, Raman, Rayleigh and fluorescence emission is a modified Fano profile where the typical lineshape has an additional Lorentzian contribution. Expressions to extract model parameters from a set of relevant observables are given.

In a set of seminal papers spanning from 1935 to 1961, Beutler [1], Fano [2, 3] and Friederichs [4] laid the basis of the theory to describe the absorption lineshapes of atomic photoionization experiments. These lineshapes present marked asymmetries which could not be explained by a simple Lorentzian resonance. The explanation was attributed to an interference between two photo-ionization pathways: one where the atom is ionized directly from its ground state and one where it is first excited to a higher discrete state which then ionizes (auto-ionizing states). The minimal Fano model consists in a discrete excited state coupled to a continuum set of excited states, both types of states being reachable by photo-excitation from the ground state. The resulting photo-fragmentation cross-section as a function of the excitation laser frequency ω_L is known as the Beutler-Fano or Fano profile:

$$h(\epsilon; q) = \frac{(q + \epsilon)^2}{\epsilon^2 + 1}, \quad (1)$$

where q is the ratio of the transition dipole moment of the ground-discrete and ground-continuous transitions, and $\epsilon = (\hbar\omega_L - E_e)/\gamma$ where E_e is the energy of the discrete state relative to the ground state and $\gamma = n\pi V^2$ is the linewidth of the excited state, induced by its coupling (per unit of energy) nV^2 to the continuum set of states, n being the density of states.

Since the original photoionization experiments, the Beutler-Fano profile has been observed in an ever increasing variety of physical systems, and in particular in nanoscale structures [5, 6]. These include plasmonic nanostructures [7–9], quantum dots, decorated nanoparticles [10] and spin filters [11], to name a few. Although the Fano theory was built on a scattering framework where the observable was the population on the contin-

uum (i.e. the ionized electrons), the result continued to be applied (with remarkable success) to dissipative, non-scattering systems where the observable was not always the population in the continuum of states. As noted by A. E. Miroshnichenko in 2010, “*a suitable theory for a quantitative description of these cases is still lacking*” [5].

Some attempts to supplement the Fano model with dissipation processes have already been made. First by Fano himself in 1963 [12] in a less-known paper, where the objective was to model pressure lineshape broadening by atomic collisions. In this paper, only pure dephasing was considered which amounts to considering solely elastic collisions. In the eighties, Agarwal et al. [13] included population relaxation from the discrete excited state to an additional discrete state to model the competition between atomic photo-ionization and spontaneous emission. K. Rzyzewski and J. H. Eberly [14] considered pure dephasing using a Wiener-Levy stochastic process to describe phase fluctuations. More recently Kroner et al. [15] and Zhang et al. [16] included a general dissipation process for a system of semiconductor quantum dots but the equations were solved approximatively by neglecting the population on the continuum set of states. It is worth noting that these three last works focus on intense field effects, which will not be addressed in the present letter and will be the subject of a future work.

In this letter, we solve exactly the Fano dissipation problem for weak field, fulfilling the conditions for absorption, Raman, Rayleigh and fluorescence spectroscopies. Within the wideband approximation to describe the coupling to the continuum, we obtain explicit and simple expressions for all optical observables, such that they can be used explicitly by experimentalists, notably

to directly obtain the system parameters. For this, we solve the dynamics of the quantum system with energy levels in a Fano like configuration and coupled to a bath which induces excited states relaxation and pure dephasing. The system density matrix evolution is described in the Born-Markov approximation, by the Liouville equation in Lindblad form [17].

Although our formalism is general and can be applied to a variety of systems, an important motivation is the type of architectures encountered in light harvesting systems called Grätzel or dye-sensitized solar cells [18, 19], where a molecule is adsorbed to a semiconductor surface. In most important physical realizations, the electronic ground state of this hybrid system is an isolated quantum state located in the semiconductor energy gap while the excited states can be considered as superpositions of localized molecular excited states and delocalized semiconductor conduction band states [19, 20]. Evidence suggests that such a model with minor modifications could also account for molecules on metal nanoparticles [10, 21, 22]. Be it for solar energy applications, electronics or sensors, there is strong evidence that the details of the interface distinguish functioning from non-functioning devices [23].

The energy levels of our model, along with the possible transitions, are shown in Figure 1. A discrete excited state $|e\rangle$ with energy E_e is coupled to a continuum of states $|k\rangle$ with energy E_k . These states can be reached from a ground state $|g\rangle$ through laser excitation. A submanifold (typically vibrational) $|\nu\rangle$ with energy E_ν is included in the electronic ground state to open inelastic scattering channels as $|\nu\rangle \rightarrow |\nu'\rangle$. The Hamiltonian is:

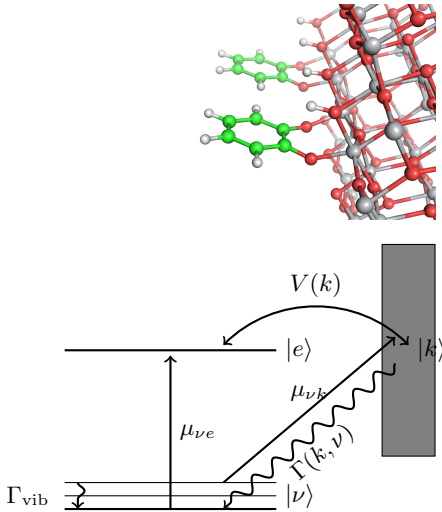


FIG. 1: Energy levels and transitions of a Fano model with dissipation, including a vibrational ground state manifold, a discrete excited state and a continuum (bottom). A particular realization of a Fano system with dissipation is a molecule adsorbed on a metal oxide semiconductor, here two catechol molecules on a (101) anatase TiO_2 surface (top)

$$H = H_0 + H_V + H_F \quad (2)$$

$$\begin{aligned} H_0 &= \sum_{\nu} E_{\nu} |\nu\rangle\langle\nu| + E_e |e\rangle\langle e| + \int dk E_k |k\rangle\langle k| \\ H_V &= \int dk [V(k) |e\rangle\langle k| + V^*(k) |k\rangle\langle e|] \\ H_F &= F \sum_{\nu} [\mu_{\nu e} \cos(\omega_L t) |\nu\rangle\langle e| + \mu_{\nu e}^* \cos(\omega_L t) |e\rangle\langle \nu|] \\ &\quad + F \sum_{\nu} \int dk [\mu_{\nu k} \cos(\omega_L t) |\nu\rangle\langle k| + \mu_{\nu k}^* \cos(\omega_L t) |k\rangle\langle \nu|] \end{aligned} \quad (3)$$

where H_0 is the site Hamiltonian, H_V is the coupling of the excited state to the continuum, for simplicity, in the following, we will consider that $V(k) = \langle e|H_V|k\rangle$ is real. H_F is the interaction with the incident radiation field of frequency ω_L , allowing transitions from the ground state to the discrete excited state $\nu \leftrightarrow e$ and to the continuum of states $\nu \leftrightarrow k$, $\mu_{ij} = \langle i|\mu|j\rangle$ is the transition dipole moment between states i and j and F is the field amplitude.

The originality of our model consists in taking into account a possible population relaxation from the continuum to the ground state at a rate $\Gamma(k, \nu)$, and pure dephasings. When the photo-excitation involves an electron, this relaxation is mainly the result of the electron-hole Coulombic attraction followed by the thermal relaxation through the phonons of the environment. We phenomenologically capture this dissipation process using a superoperator of Lindblad [17] form, which ensures the trace-preserving and complete positivity of the dynamical map, and solve the evolution of the density matrix with Liouville's equation:

$$\frac{\partial \rho}{\partial t} = \mathcal{L}(t)\rho \quad (4)$$

where $\mathcal{L}(t) = \mathcal{L}_H(t) + L^D$, with $\hbar\mathcal{L}_H = -i(\mathbb{1} \otimes H^T(t) - H(t) \otimes \mathbb{1})$, $L^D = L_k^D + L_{\text{vib}}^D + L_{\text{pure}}^D$

$$\begin{aligned} L_k^D &= \sum_{\nu} \int dk \Gamma(k, \nu) \left\{ A(k, \nu) \otimes A(k, \nu) \right. \\ &\quad \left. - \frac{1}{2} [1 \otimes A^\dagger(k, \nu) A(k, \nu) + A^\dagger(k, \nu) A(k, \nu) \otimes 1] \right\}, \end{aligned} \quad (5)$$

$$\begin{aligned} L_{\text{vib}}^D &= \sum_{\nu \neq 0} \Gamma_{\text{vib}} \left\{ A(\nu, 0) \otimes A(\nu, 0) \right. \\ &\quad \left. - \frac{1}{2} [1 \otimes A^\dagger(\nu, 0) A(\nu, 0) + A^\dagger(\nu, 0) A(\nu, 0) \otimes 1] \right\} \end{aligned} \quad (6)$$

and

$$\begin{aligned} L_{\text{pure}}^D &= -\sum_{\nu} \gamma_{e\nu} [|e\rangle\langle e| \otimes |\nu\rangle\langle\nu| + |\nu\rangle\langle\nu| \otimes |e\rangle\langle e|] \\ &\quad - \sum_{\nu} \int dk \gamma_{k\nu} [|k\rangle\langle k| \otimes |\nu\rangle\langle\nu| + |\nu\rangle\langle\nu| \otimes |k\rangle\langle k|] \\ &\quad - \int dk \gamma_{ke} [|k\rangle\langle k| \otimes |e\rangle\langle e| + |e\rangle\langle e| \otimes |k\rangle\langle k|], \end{aligned} \quad (7)$$

where H^T denotes the transpose of H , $A(i, j) = |j\rangle\langle i|$ are the jump operators and $\Gamma(k, \nu)$ is the population

relaxation rate from state $|k\rangle$ to $|\nu\rangle$. The superoperator L_{vib}^D relaxes the ground states vibrational manifold and $\Gamma_{\nu 0}$ is the population relaxation rate within the electronic ground state manifold. γ_{ij} are the pure dephasing rates for the ij coherences. We have used the isomorphism $L\tilde{\rho}R \rightarrow L \otimes R^T \rho$, where ρ is the column form of the matrix $\tilde{\rho}$ through the correspondence: $|l\rangle\langle m| \leftrightarrow |l\rangle \otimes |m\rangle \equiv ||lm\rangle$ [24].

Non-radiative and radiative transitions from the electronic excited state $|e\rangle$ to the ground states $|\nu\rangle$ exist. They have been left out for simplicity, although their inclusion can be done straightforwardly. Furthermore, in most cases of interest, the electronic coupling V induces an effective population relaxation rate $2\pi nV^2/\hbar$ associated to electron injection into the semiconductor band which is much larger than the $e \rightarrow \nu$ rate corresponding to the direct relaxation mechanism, hence justifying this simplification [25].

The optical response (absorption and emission spectra) is obtained through the Fourier transform of the field two-times correlation function which in the far field is proportional to the dipole two-times correlation function. Using the quantum regression theorem [26–28], the emitted light differential scattering cross-section can be written in the steady-state of the system as [29, 30]:

$$\frac{d^2\sigma}{d\Omega d(\hbar\omega)} = A(\theta) \times \sum_{a \in e, k} \sum_{b \in \nu} \mu_{ab}^2 \sum_{r \in \nu, e, k} \text{Re}[\rho_{ra} G_{ab,rb}(-i(\omega - \omega_L))], \quad (8)$$

with $A(\theta) = \frac{\omega^4 \sin^2 \theta}{I_{\text{in}} 8\pi^3 c^3 \epsilon_0 \hbar}$, $d\Omega$ the element of solid angle, I_{in} the incident laser intensity, θ the polar angle in spherical coordinates, ρ the steady state density matrix and $G(z) = (z\mathbb{1} - i\Omega_L - L)^{-1}$ the resolvent, which is the Laplace transform of the evolution superoperator, corresponding to the time-independent Liouvillian $L = e^{i\Omega_L t} \mathcal{L}(t) e^{-i\Omega_L t}$ in the rotating-wave approximation (RWA), which consists in removing resonant oscillating prefactors and discarding non resonant terms. The Ω_L matrix is a diagonal matrix with $\pm\omega_L$ for excited(ground)-ground(excited) coherences, and zero elsewhere. In summary, in order to obtain the optical emission we need to calculate the resolvent and the steady-state density matrix, which we do next. An explicit expression for $G(z)$ is obtained by separating L into its diagonal and non-diagonal parts. While the diagonal contribution leads to a trivial calculation of its resolvent, the non-diagonal contribution is worked out through a Dyson equation to all orders in the field-free coupling and to second order in the field interaction. As for the steady-state density matrix ρ , it appears as the kernel of the Liouvillian within the RWA, that is $(-i\Omega_L - L)\rho = 0$, which can in turn also be expanded to second order in the field, with the help of the previously calculated resolvent $G(z)$ [25].

In principle, the above method allows to calculate the optical response for arbitrary couplings and density of states. Nevertheless, for many materials, the wideband approximation, which considers k -independent couplings and a constant density of states, can faithfully reproduce experimental measurements. This was the same approximation which allowed a closed analytic form in the original Fano model [3] and which has been used in all previous partial attempts to solve the Fano-dissipative problem [12–16]. We introduce the notation $\Gamma_{c\nu} = \Gamma(k, \nu)$ and $\mu_{\nu c} = \mu_{\nu k}$ for the k -independent parameters.

A straightforward but tedious calculation [25] yields all the terms needed to calculate the absorption spectrum and the emission differential cross-section (Eq (8)). The absorption and emission profiles, which carry the ω_L dependence, can be expressed in a compact and simple form in terms of the following function:

$$f(\epsilon, q, \eta, \alpha) = \alpha \frac{(q + \epsilon)^2}{\epsilon^2 + 1} + \eta \frac{q + 1}{\epsilon^2 + 1} \quad (9)$$

which is a linear combination of a Fano profile (first term) and a Lorentzian (second term); q being the Fano asymmetry parameter and ϵ the normalized incident laser energy. α (which can only take the values 0 and 1) and η are weighting coefficients for the Fano and Lorentzian components, respectively.

The sum of excited state populations ($\rho_{ee} + \int dk \rho_{kk}$) can be written as:

$$N_{\text{excited}} = B^{\text{abs}} f(\epsilon, q, \eta, \alpha) \quad (10)$$

where B^{abs} is a constant [25], ϵ and q are the standard Fano parameters ($\epsilon = (E_e - \hbar\omega_L)/\gamma$, $\gamma = n\pi V^2$, $q = \mu_{0e}/(n\pi V \mu_{0c})$), $\alpha = 1$, and $\eta = (\sum_{\nu} \Gamma_{c\nu})/(4\pi nV^2)$. We can obtain the extinction coefficient β measured in optical absorption measurements using arguments of detailed balance [25]:

$$\beta = \frac{n\pi\mu_{0c}^2}{c\epsilon_0\hbar} \hbar\omega_L f(\epsilon, q, \eta = 0, \alpha = 1) \quad (11)$$

where c is the speed of light and ϵ_0 the vacuum permittivity. The differential cross sections for the three processes Rayleigh, Raman and fluorescence can all be expressed referring to the same functional form:

$$\frac{d^2\sigma^i}{d\Omega d(\hbar\omega)} = A(\theta) B_{\nu}^i R(\omega, \omega_0^i, \Delta^i) f(\epsilon^i, q^i, \eta^i, \alpha^i) \quad (12)$$

where i = Rayleigh, Raman or fluorescence. The expression for emission has 3 parts: $A(\theta)B_{\nu}^i$ is a prefactor [25], $R(\omega, \omega_0, \Delta) = \frac{\Delta}{\pi} [(\omega - \omega_0)^2 + (\Delta)^2]^{-1}$ is a normalized Lorentzian of central frequency ω_0 and half-width Δ which gives the emission lineshape (for a fixed incident laser frequency), and $f(\epsilon, q, \eta, \alpha)$ which gives the profile - the signal integrated over the emitted frequency - and carries all the dependence of the incident laser frequency ω_L .

We first discuss the characteristic function f of the population given by equation 10. The result is the combination of a standard Fano profile, and a Lorentzian. The signature of the relaxation process is embodied in the parameter η . Its physical meaning is the ratio of the relaxation rate to the injection rate into the continuum. When $\eta \gg 1$ the relaxation quenches the population of the continuum and therefore suppresses the Fano interference signal giving rise to a pure Lorentzian lineshape. When $\eta \ll 1$, we recover the original Fano profile. Figure 2 shows normalized population profiles as given by Eq. (10), for several values of q and η . As $\eta \rightarrow 0$, the curve approaches the standard Fano profile while $\eta = 1$ shows the Fano with a Lorentzian contribution for different values of the q parameter.

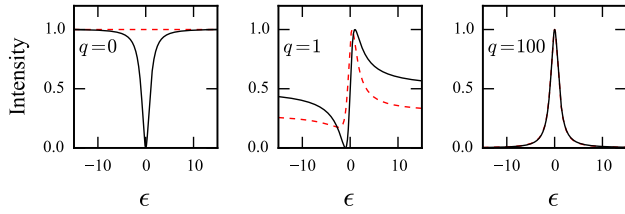


FIG. 2: Characteristic function for absorption or Raman emission for $\eta = 0$ (solid black) and $\eta = 1$ (red dashed) for $q = 0, 1, 100$ (intensities are normalized).

For the emission processes, we separate the full optical response given by Eq. (8) into several components according to their central emission frequency ω_0^i of the lineshape functions $R(\omega, \omega_0^i, \Delta^i)$. The Rayleigh process corresponds to $\omega_0^{\text{Ray}} = \omega_L$ and the Raman process to $\omega_0^{\text{Ram}} = \omega_L - \omega_{\text{vib}}$, ($\hbar\omega_{\text{vib}} = E_1 - E_0$). Contrary to the Rayleigh and Raman scattering which are coherent processes, fluorescence corresponding to a radiative transition from excited population is incoherent. This stationary population can only exist if in addition to population relaxation, pure dephasing processes are taken into account ($\gamma_{ij} \neq 0$ in Eq. (7)). The population of the discrete excited state leads to an emission at E_e/\hbar and at $E_e/\hbar - \omega_{\text{vib}}$ central frequencies. The continuum states are populated at the laser frequency ω_L and therefore give a fluorescence emission with central frequencies at ω_L and $\omega_L - \omega_{\text{vib}}$. We note that the fluorescence from the continuum states occurs at the same central frequencies as the Rayleigh and Raman scattering, but can be distinguished by their respective lineshape widths Δ^i . For Rayleigh, the width comes from the laser linewidth, $\Delta^{\text{Ray}} = \delta$, and for the Raman the width is given by the inverse lifetime of the vibrationally excited state $\nu = 1$, $\Delta^{\text{Ram}} = \Gamma_{\text{vib}}/2$. The width of the fluorescence lineshape is dominated by the excited state population lifetime: for the emission at ω_L the width is $\Delta^{\text{fluor},c0} = \sum_{\nu} \Gamma_{c\nu}$ and for the emission at $\omega_L - \omega_{\text{vib}}$ the width is $\Delta^{\text{fluor},c1} = \sum_{\nu} \Gamma_{c\nu} + \Gamma_{\text{vib}}/2$. All the param-

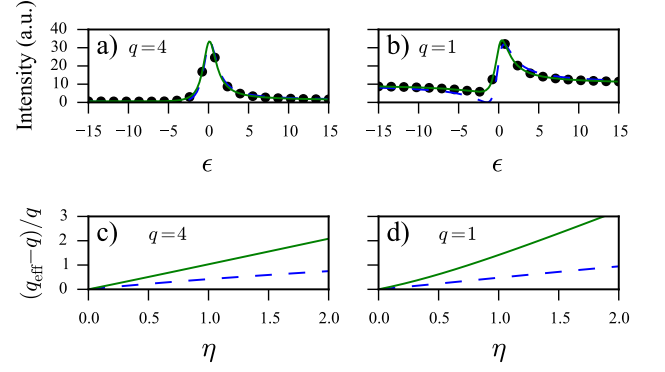


FIG. 3: Comparison between different Fano models. Top: fits of the profile presented in this paper Eq. (9) with a) $q = 4$ and b) $q = 1$, with $\eta = 1$ by a standard (blue dashed) or a shifted Fano profiles (solid green). Bottom: relative differences between the extracted q_{eff} and the actual q value for c) $q = 4$ and d) $q = 1$ for the standard (blue dashed) or the shifted Fano profiles (solid green).

eters for each emission component given by Eq. (12) are collected in Table I.

The parameters of the model can be extracted from spectroscopic measurements. By fitting the profiles, we can get γ , q , B^{abs} , B^{Ram} , B^{Ray} , F (experimental parameter), η^{Ray} , and η^{Ram} (Table I and S.M. [25]). From these, there are various ways to obtain the model parameters, for instance:

$$\begin{aligned} \sum_{\nu=0}^1 \Gamma_{c\nu} &= \frac{B^{\text{Ray}}}{(B^{\text{abs}})^2} \frac{F^2}{2\hbar}, \quad \sqrt{n}V = \sqrt{\frac{\gamma}{\pi}} \\ \sqrt{n}\mu_{0c} &= \sqrt{\frac{B^{\text{Ray}}}{\pi B^{\text{abs}}}}, \quad \mu_{0e} = \sqrt{\frac{B^{\text{Ray}}\gamma}{B^{\text{abs}}}} q \\ \sqrt{n}\mu_{1c} &= \sqrt{\frac{B^{\text{Ram}}}{\pi B^{\text{abs}}}}, \quad \mu_{1e} = \frac{8\eta^{\text{Ram}}\gamma B^{\text{abs}} B^{\text{Ram}} \hbar}{\pi B^{\text{Ray}} F^2} \end{aligned} \quad (13)$$

We now discuss how important is to include the Lorentzian term arising from dissipation in addition to the standard Fano profile. In Fig. 3, we present a profile with our model Eq. (10) with a given set of parameters and fit it both with a standard Fano model $h(\epsilon; q_{\text{eff}})$ (Eq. (1)) and with a shifted Fano model $\frac{1}{N}[h(\epsilon; q_{\text{eff}}) + D]$. The shifted Fano fitting is usually performed in optical measurements and corresponds to a constant background subtraction. Below, we calculate the relative error between the extracted value of the Fano asymmetry parameter, which we call q_{eff} , and the original q as a function of the Lorentzian weight factor η . We show that even when the fitting is very good, the extracted parameters can be off by a factor of two for $\eta = 1$. This definitely shows the importance of including properly the dissipation in the Fano model.

In conclusion, we expect that the equations will motivate the experimentalists to extract system parameters

Model:	Lineshape		Profile			
	Center frequency	Width	Laser frequency	Asymmetry parameter	Fano weight α	Lorentzian weight η
Standard:			ϵ	q	1	—
Excited state: populations			ϵ	q	1	η
Rayleigh:	ω_L	δ	ϵ	q	1	$\frac{\mu_{0e}^2}{n\mu_{0c}^2} \eta$
Raman:	$\omega_L - \omega_{\text{vib}}$	$\Gamma_{\text{vib}}/2$	ϵ	q	1	$\frac{\mu_{1e}^2}{n\mu_{1c}^2} \eta$
Fluorescence:	$(E_e - E_0)/\hbar$	$n\pi V^2/\hbar + \gamma_{e0}$	$\frac{\epsilon(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	$\frac{q(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	0	$(\frac{n\pi V^2}{n\pi V^2 + \hbar\gamma_{e0}})^2 \eta$
discrete	$(E_e - E_1)/\hbar$	$n\pi V^2/\hbar + \gamma_{e1} + \Gamma_{\text{vib}}/2$	$\frac{\epsilon(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	$\frac{q(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	0	$(\frac{n\pi V^2}{n\pi V^2 + \hbar\gamma_{e0}})^2 \eta$
Fluorescence :	ω_L	$\sum_{\nu} \Gamma_{c\nu} + 2\gamma_{e0}$	$\frac{\epsilon(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	$\frac{q(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	1	$\frac{\gamma_{e0}^2}{(n\pi V^2/\hbar + \gamma_{e0})^2} \frac{1}{q^2 + 1}$
continuum	$\omega_L - \omega_{\text{vib}}$	$\sum_{\nu} \Gamma_{c\nu} + \gamma_{e0} + \gamma_{e1} + \Gamma_{\text{vib}}/2$	$\frac{\epsilon(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	$\frac{q(n\pi V^2)}{n\pi V^2 + \hbar\gamma_{e0}}$	1	$\frac{\gamma_{e0}^2}{(n\pi V^2/\hbar + \gamma_{e0})^2} \frac{1}{q^2 + 1}$

TABLE I: Parameters for all optical processes depicted in Eqs. (10) (12). The parameters are expressed as a function of $\epsilon = (\hbar\omega_L - E_e)/(n\pi V^2)$, $q = \mu_{0e}/(n\pi V\mu_{0c})$ and $\eta = \sum_{\nu} \Gamma_{c\nu}/(4n\pi V^2)$.

which were not accessible previously, from routine optical spectroscopies, characterizing with increasing precision the discrete-continuum interface both relevant in devices and interesting from a fundamental standpoint. Furthermore, our model serves as a stepping stone for further theoretical studies: optical response beyond the wide-band approximation (near band edges for example), strong field effects relevant for plasmonics, generalization to time-dependent laser pulse sequences relevant to non-linear 2D spectroscopy and application to real systems with the help of computational tools in order to obtain ab-initio the parameters of the model.

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